

## 30mA, 40V Schottky Barrier Diode

#### **FEATURES**

- Low reverse current
- Surface mount device type
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Adapters
- For switching power supply
- · Low stored charge
- Inverter

#### **MECHANICAL DATA**

- Case: SOD-523F
- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- · Polarity: Indicated by cathode band
- Weight: 1.60 mg (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I <sub>F</sub>	30	mA	
$V_{RRM}$	40	V	
$V_F$ at $I_F = 1 \text{mA}$	0.37	V	
$T_{JMAX}$	125	°C	
Package	SOD-523F		
Configuration	Single die		









**SOD-523F** 



PARAMETER	SYMBOL	RB751M5-40	UNIT
Marking code on the device		5	
Repetitive peak reverse voltage	$V_{RRM}$	40	V
DC block voltage	V <sub>R</sub>	30	V
Forward current	I <sub>F</sub>	30	mA
Non-repetitive peak forward surge current @ t = 8.3ms	I <sub>FSM</sub>	0.2	А
Power dissipation	P <sub>D</sub>	200	mW
Junction temperature range	TJ	-55 to +125	°C
Storage temperature range	T <sub>STG</sub>	-55 to +125	°C



# RB751M5-40 Taiwan Semiconductor

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage <sup>(1)</sup>	I <sub>F</sub> = 1mA, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	0.37	V
Reverse current <sup>(2)</sup>	V <sub>R</sub> = 30V, T <sub>J</sub> = 25°C	I <sub>R</sub>	-	0.50	μA
Capacitance	$V_R = 1V$ , $f = 1MHz$	С	2	-	pF

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE	PACKAGE	PACKING	
RB751M5-40 RSG	SOD-523F	8K / 7" Reel	



#### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

Fig.1 Typical Forward Characteristics

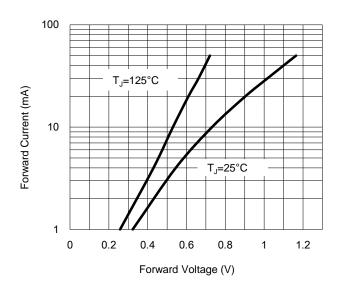
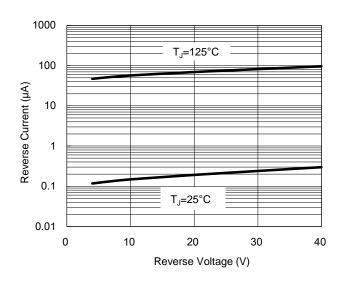


Fig.2 Typical Reverse Characteristics



**Fig.3 Typical Capacitance Characteristics** 

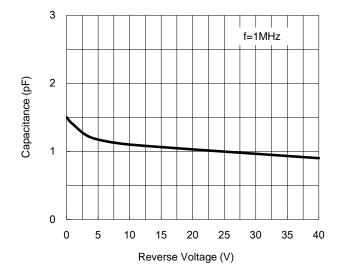
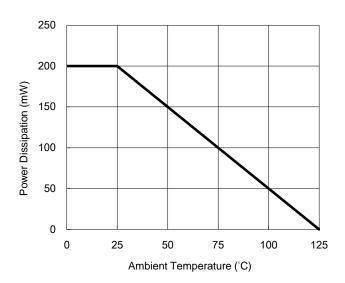


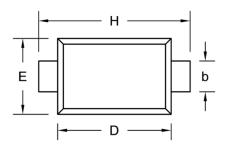
Fig.4 Power Derating Curve

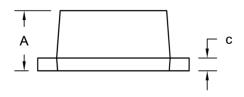




#### **PACKAGE OUTLINE DIMENSION**

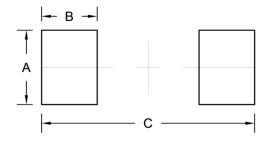
**SOD-523F** 





#### Unit (mm) Unit (inch) DIM. Min. Max. Min. Max. 0.50 0.77 0.020 0.030 Α b 0.25 0.40 0.010 0.016 0.07 0.20 0.003 0.008 С D 1.10 1.30 0.043 0.051 0.70 Ε 0.90 0.028 0.035 1.50 Н 1.70 0.059 0.067

#### **SUGGEST PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
Α	0.80	0.031
В	0.60	0.024
С	2.30	0.091



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